



IFW

Docket No.: 5232-0102PUS1
(PATENT)

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of:
Hiroaki MATSUMURA et al.

Application No.: 10/563,811

Confirmation No.: 1910

Filed: January 9, 2006

Art Unit: N/A

For: NITRIDE SEMICONDUCTOR LASER
DEVICE AND LASER APPARATUS USING
THE SAME

Examiner: Not Yet Assigned

LETTER

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

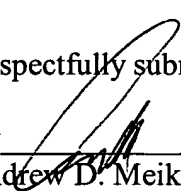
Sir:

Subsequent to the filing of the above-identified application on January 9, 2006, attached hereto is an English translation of the International Preliminary Examination Report (Form PCT/IPEA/409) that should be made of record in the present application.

If necessary, the Commissioner is hereby authorized in this, concurrent, and future replies, to charge payment or to credit any overpayment to Deposit Account No. 02-2448 for any additional fees required under 37 C.F.R. § 1.16 or under 37 C.F.R. § 1.17; particularly, extension of time fees.

Dated: September 6, 2006

Respectfully submitted,

By 
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